

# **Bridge Rectifiers**

#### **Features**

- UL recognition, file #E230084
- Thin single in-line package
- Glass passivated chip junction
- High surge current capability
- Solder dip 275 °C max. 7 s, per JESD 22-B106

#### **Typical Applications**

General purpose use in AC/DC bridge full wave rectification for switching power supply, home appliances, office equipment, industrial automation applications.

#### **Mechanical Data**

• Package: 6KBJ

Molding compound meets UL 94 V-0 flammability

rating, ·

• **Terminals**: Tin plated leads, solderable per

J-STD-002 and JESD22-B102
• Polarity: As marked on body

#### ■Maximum Ratings (Ta=25°C Unless otherwise specified)

PARAMETER		SYMBOL	UNIT	GBJ1010D	
Device marking code				GBJ1010D	
Maximum Repetitive Peak Reverse Voltage		VRRM	V	1600	
Maximum RMS Voltage		VRMS	V	1120	
Maximum DC blocking Voltage		VDC	V	1600	
Average rectified output current @60Hz sine wave, R-load	With heatsink Tc =110°C	· IO	Α	10	
	Without heatsink Ta =25°C			3.5	
Forward Surge Current (Non-repetitive) @60Hz Half-sine wave,1 cycle, Tj=25°C		IFSM	А	160	
Forward Surge Current (Non-repetitive) @1ms, square wave, 1 cycle, Tj=25°C				320	
Current squared time @1ms≤t≤8.3ms Tj=25°C, Rating of per diode		l²t	A <sup>2</sup> s	127	
Storage temperature		T <sub>stg</sub>	°C	-55 ~ +150	
Junction temperature		Tj	°C	-55 ~ +150	
Dielectric strength @ Terminals to case, AC 1 minute		Vdis	KV	2.5	
Mounting torque @Recommend torque: 5kg·cm		Tor	kg∙cm	8	



**■Electrical Characteristics** (Ta=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	TEST CONDITIONS	GBJ1010D
Maximum instantaneous forward voltage drop per diode	VF	٧	IFM=5.0A	1.1
Maximum DC reverse current at rated DC blocking voltage per diode	IR	μА	T <sub>j</sub> =25°C	5
			T <sub>j</sub> =125°C	500
Typical junction capacitance	Cj	pF	Measured at 1MHz and Applied Reverse Voltage of 4.0 V.D.C	42

### ■Thermal Characteristics $(T_a=25^{\circ}\mathbb{C} \text{ Unless otherwise specified})$

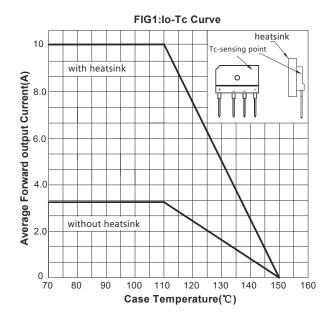
PARAMETER		SYMBOL	UNIT	GBJ1010D
Thermal	Between junction and ambient, Without heatsink	RθJ-A	0 <b>C</b> 0 A 1	18.0
	Between junction and case, With heatsink	R <sub>0</sub> J-C	°C/W	2.0

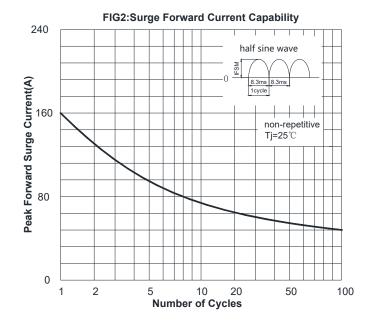
Note: Device mounted on 75mm x 45mm x 5.5mm Aluminum Plate Heatsink.

**■Ordering Information** (Example)

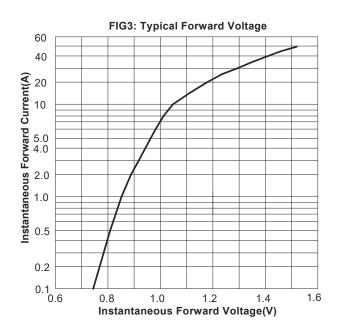
PREFERED P/N	PACKING CODE	UNIT WEIGHT(g)	MINIIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
GBJ1010D	B1	Approximate 6.5	15	750	1500	TUBE

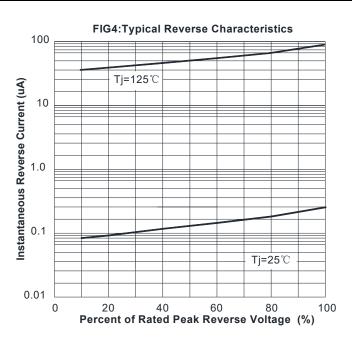
### ■ Characteristics(Typical)



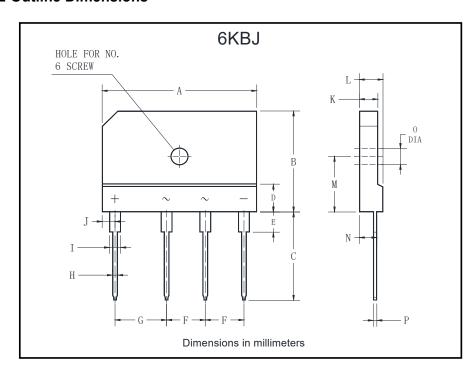








#### **■** Outline Dimensions



6KBJ						
Dim	Min	Max				
Α	29.7	30.3				
В	19.7	20.3				
С	17.0	18.0				
D	4.8	5.8				
Е	3.8	4.2				
F	7.3	7.7				
G	9.8	10.2				
Н	0.9	1.1				
I	2.0	2.4				
J	2.3	2.7				
K	3.4	3.8				
L	4.4	4.8				
М	10.8	11.2				
N	3.1	3.7				
0	3.1	3.4				
Р	0.6	0.8				



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